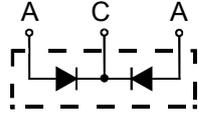
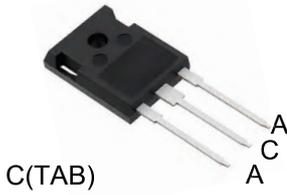
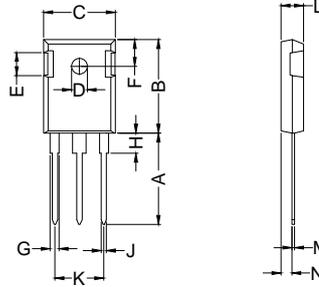


MUR3020PT, MUR3030PT, MUR3040PT, MUR3060PT

Ultra Fast Recovery Diodes



Dimensions TO-247AD



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.620	0.640
ØD	3.15	3.65	0.124	0.144
E	4.32	5.49	0.170	0.216
F	5.40	6.30	0.213	0.248
G	1.65	2.18	0.065	0.086
H	3.80	4.50	0.150	0.177
J	1.00	1.40	0.039	0.055
K	10.80	11.10	0.425	0.437
L	4.70	5.30	0.185	0.209
M	0.40	0.80	0.016	0.031
N	1.50	2.49	0.059	0.098

A=Anode, C=Cathode, TAB=Cathode

	V _{RSM} V	V _{RRM} V
MUR3020PT	200	200
MUR3030PT	300	300
MUR3040PT	400	400
MUR3060PT	600	600

Symbol	Test Conditions	Maximum Ratings	Unit	
I _{FRMS}	T _{VJ} =T _{VJM}	25	A	
I _{FAVM}	T _C =100°C; rectangular, d=0.5	30		
I _{FRM}	t _p <10µs; rep. rating, pulse width limited by T _{VJM}	150		
I _{FSM}	T _{VJ} =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	100 110	A
	T _{VJ} =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	85 95	
I ² t	T _{VJ} =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	50 50	A ² s
	T _{VJ} =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	36 37	
T _{VJ} T _{VJM} T _{stg}		-40...+150 150 -40...+150	°C	
P _{tot}	T _C =25°C	62	W	
M _d	Mounting torque	0.4...0.6	Nm	
Weight	typical	6	g	



MUR3020PT, MUR3030PT, MUR3040PT, MUR3060PT

Ultra Fast Recovery Diodes

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I _R	T _{VJ} =25°C; V _R =V _{RRM}		50	uA
	T _{VJ} =25°C; V _R =0.8·V _{RRM}		25	uA
	T _{VJ} =125°C; V _R =0.8·V _{RRM}		3	mA
V _F	I _F =15A; T _{VJ} =150°C		1.5	V
	T _{VJ} =25°C		1.7	
V _{TO}	For power-loss calculations only		1.12	V
r _T	T _{VJ} =T _{VJM}		23.2	mΩ
R _{thJC} R _{thCK} R _{thJA}		0.5	2	K/W
			60	
t _{tr}	I _F =1A; -di/dt=50A/us; V _R =30V; T _{VJ} =25°C	35	50	ns
I _{RM}	V _R =350V; I _F =15A; -di _F /dt=100A/us; L≤0.05uH; T _{VJ} =100°C	4	4.4	A

FEATURES

- * International standard package JEDEC TO-247AD
- * Glass passivated chips
- * Very short recovery time
- * Extremely low switching losses
- * Low I_{RM}-values
- * Soft recovery behaviour
- * RoHS compliance

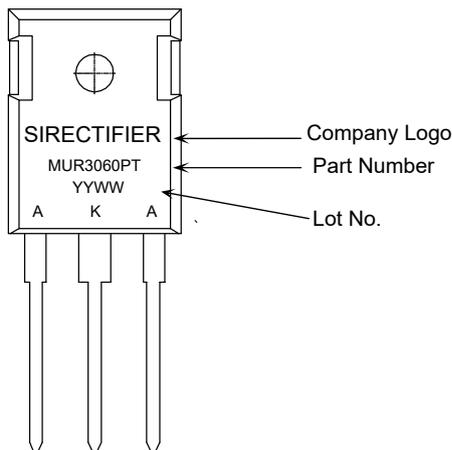
APPLICATIONS

- * Rectifiers in switch mode power supplies (SMPS)
- * Uninterruptible power supplies (UPS)
- * Ultrasonic cleaners and welders

ADVANTAGES

- * High reliability circuit operation
- * Low voltage peaks for reduced protection circuits
- * Low noise switching
- * Low losses
- * Operating at lower temperature or space saving by reduced cooling

MARKING



ORDERING INFORMATION

Part Number	Package	Shipping	Marking Code
MUR3060PT	TO-247AD	30pcs / Tube	MUR3060PT

Sirectifier®

MUR3020PT, MUR3030PT, MUR3040PT, MUR3060PT

Ultra Fast Recovery Diodes

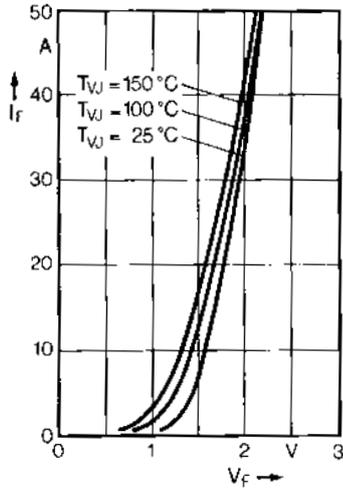


Fig. 1 Forward current versus voltage drop.

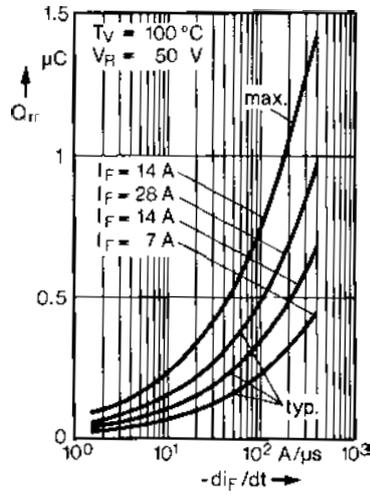


Fig. 2 Recovery charge versus $-di_F/dt$.

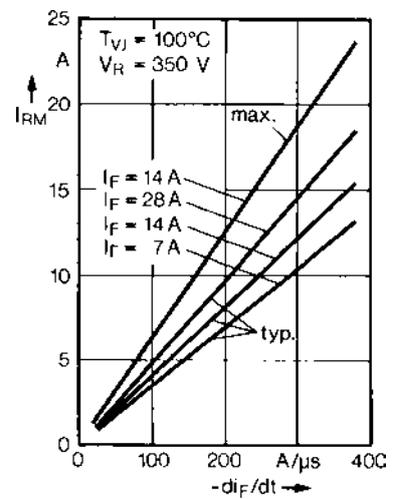


Fig. 3 Peak reverse current versus $-di_F/dt$.

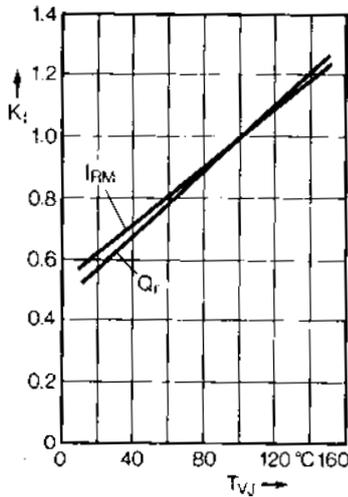


Fig. 4 Dynamic parameters versus junction temperature.

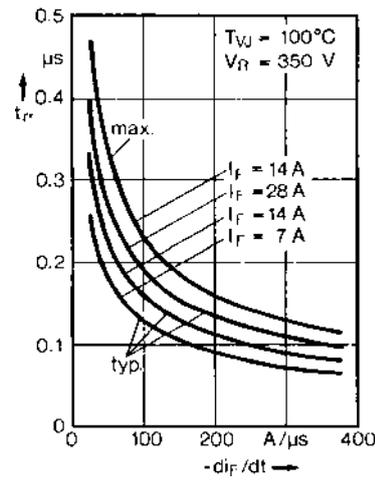


Fig. 5 Recovery time versus $-di_F/dt$.

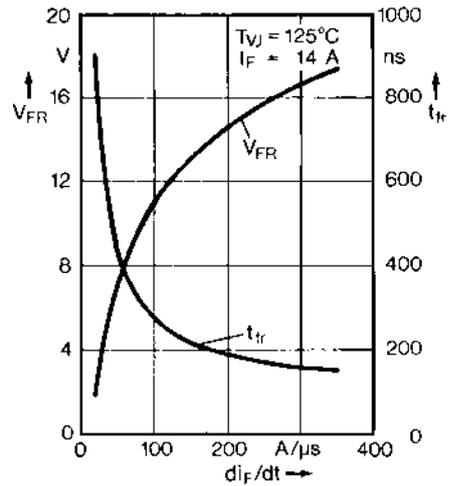


Fig. 6 Peak forward voltage versus di_F/dt .

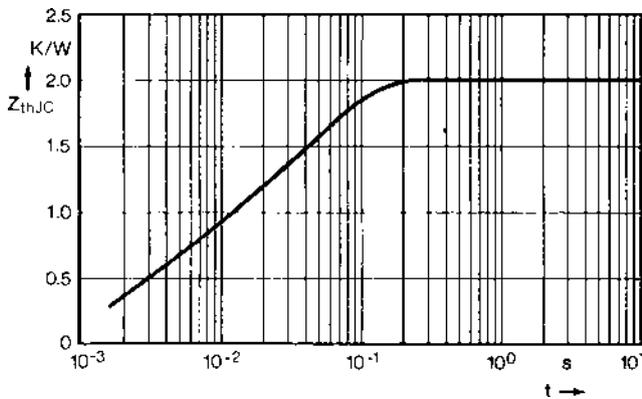


Fig. 7 Transient thermal impedance junction to case.